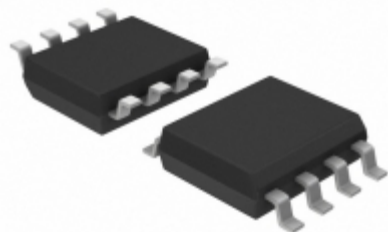



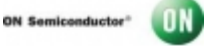
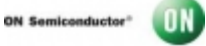





	<h2 style="color: red;">NTMS5835NLR2G</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">NTMS5835NLR2G</a>
	<b>Hersteller / Marke:</b>	<a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 40V 9.2A 8SOIC
	<b>Datenblätter:</b>	 <a href="#">NTMS5835NLR2G.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
<p>Image may be representation. See specs for product details.</p>	<b>Lagerzustand:</b>	New original, 101677 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS

### Spezifikationen

Teilenummer	<a href="#">NTMS5835NLR2G</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 40V 9.2A 8SOIC
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	101677 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SOIC
Verlustleistung (max)	1.5W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	9.2A (Ta)
Rds On (Max) @ Id, Vgs	10 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	50nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2115pF @ 20V
Verpackung	Tape & Reel (TR)













NTMS5835NLR2G ist neu im Original, Suche NTMS5835NLR2G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMS5835NLR2G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMS5835NLR2G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTMS5P02R2G SOP8</b> ON NTMS5P02R2G SOP8 ON</p>	 <p><b>NTMS5835NL</b> AMI Semiconductor / ON Semiconductor NTMS5835NL ON</p>	 <p><b>NTMS5P02</b> AMI Semiconductor / ON Semiconductor NTMS5P02 ON</p>	 <p><b>NTMS4P01R2G</b> O NTMS4P01R2G O</p>
 <p><b>NTMS4N01R2G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 20V 3.3A 8-SOIC</p>	 <p><b>NTMS4P01R2</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 12V 3.4A 8-SOIC</p>	 <p><b>NTMS5P02R2G</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 3.95A 8-SOIC</p>	 <p><b>NTMS4N01R2</b> ON NTMS4N01R2 ON</p>

### heiße Teile

Mehr

 NTMS4503NR2G	 NTMS4700NR	 NTMS4700NR2G	 NTMS4704NR2G	 NTMS4705NR2G
 NTMS4706NR2G	 NTMS4800NR2G	 NTMS4801N	 NTMS4801NR2G	 NTMS4802N
 NTMS4802NR2G	 NTMS4807N	 NTMS4807NR2G	 NTMS4816N	 NTMS4816NG
 NTMS4816NR2G	 NTMS4840NR2G	 NTMS4872NR2G	 NTMS4873NFR2G	 NTMS4916AS001
 NTMS4916N	 NTMS4916NR2G	 NTMS4916UT001	 NTMS4917NR2G	 NTMS4917UT001
 NTMS4920N	 NTMS4920NR2G	 NTMS4937N	 NTMS4937NR2G	 NTMS4939N
 NTMS4939NR2G	 NTMS4N01R2	 NTMS4P01R2G	 NTMS5835NL	 NTMS5838NLR2G
 NTMS5P02	 NTMS5P02R2	 NTMS5P02R2G	 NTMS7N03R2	 NTMS7N03R2G
 NTMS7N03R2R2G	 NTMSD2P102LR2	 NTMSD2P102R2	 NTMSD3P102R2	 NTMSD3P102R2SG
 NTMSD3P303R2	 NTMSD6N03R2G	 NTMSD6N303R2	 NTMSD6N303R2G	 NTMSD6N303R2SG

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited